MIZORAM PUBLIC SERVICE COMMISSION

TECHNICAL COMPETITIVE EXAMINATIONS FOR JUNIOR GRADE OF MIZORAM ENGINEERING SERVICE (M.E.S.) UNDER PUBLIC HEALTH DEPARTMENT, GOVERNMENT OF MIZORAM, MAY, 2019.

ELECTRONICS & COMMUNICATION ENGINEERING PAPER - I

Time Allowed: 3 hours FM: 200

SECTION - A (Multiple Choice questions)

		(100 Mar)	ks)		
All questions carry equal mark of 2 each. Attempt all questions.					
		This Section should be answered only on th	he <u>O</u> l	MR Response Sheet provided.	
1.	Whic	ch capacitor-store higher amount of energy?			
	(a)	Air capacitor	(b)	Paper capacitor	
	(c)	Mica capacitor	(d)	Plastic film capacitor	
2.	In pa	ramagnetic materials -			
	(a)	permanent magnetic dipoles exist but the negligible	inte	raction between neighbouring dipoles is	
	(b)	permanent magnetic dipole do not exist			
	(c)	permanent magnetic dipoles exist and the very strong	inte	raction between neighbouring dipoles is	
	(d)	permanent magnetic dipole moment may or	may	not exist	
3.	Ferri	tes have -			
	(a)	a low copper loss	(b)	low eddy current loss	
	(c)	low resistivity	(d)	higher specific gravity compared to iron	
4.	At a	very low temperature, a semiconductor -			
	(a)	becomes a conductor			
	(b)	becomes an insulator			
	(c)	may become a conductor or an insulator			
	(d)	will remain a semiconductor			
5.	The	colour code on a carbon resistor is red-red-	blacl	x-silver. The value of resistor is -	
	(a)	22000 W	(b)	2200 W	
	(c)	$22 \pm 5\% W$	(d)	$22 \pm 10\%$ W	
6.	The t	emperature coefficient of a thermistor -			

(d) may be positive or negative depending on its composition

(a) is positive(b) is negative

(c) zero

7.	Assertion (A): Helium, Argon and Neon are gaseous at room temperature.			
	Reason (R): The atoms in Helium, Argon and Neon are chemically extremely inactive.			
	(a) Both A and R are true and R is correct explanation of A			
	(b) Both A and R are true but R is not correct explanation of A			
	(c)	A is true but R is false		
	(d)	A is false but R is true		
8.	Nich	rome is used for -		
	(a)	overload line wires	(b)	heater coils
	(c)	lamp filaments	(d)	all of these
9.	If k is	s Boltzmann's constant and T is absolute ten	np, th	nen at room temp
	(a)	$kT \simeq 0.025 \text{ eV}$	(b)	$kT \simeq 0.5 \text{ eV}$
	(c)	$kT \simeq 1 \text{ eV}$	(d)	$kT \simeq 100 \mathrm{eV}$
10.	If the valence electron is separated from a copper atom, the remaining part of atom has a necharge of			
	(a)	1	(b)	-1
	(c)	0	(d)	+3
11.	Asse	rtion (A): Intrinsic resistivity of silicon is le	ower	than that of germanium.
	Reas	on (R): Magnitude of free electron concentr	ation	in germanium is more than that of silicon
	(a) Both A and R are true and R is correct explanation of A(b) Both A and R are true but R is not correct explanation of A			ion of A
				nation of A
	(c)	A is true but R is false		
	(d)	A is false but R is true		
12.	The	units for e_r are		
	(a)	Farads	(b)	Farads/m
		kV		
	(c)	mn	(d)	no units
13.	As th	te temperature of semiconductor is increase	d -	
		the average number of free charge carriers		eases
	 (a) the average number of free charge carriers increases (b) the average number of free charge carriers remains the same (c) the average number of free charge carriers may increase or decrease 			
				ins the same
				increase or decrease
14.	In the	In the wave mechanical theory, the maximum of the charge distribution in the ground state occurs		
	for a distance from the nucleus equal to			
	(a)	first Bohr radius	` /	second Bohr radius
	(c)	third Bohr radius	(d)	either first or second Bohr radius
15.	Asse	rtion (A): Holes are majority carriers in p t	ype	semiconductor.
		Reason (R): In p type semiconductor, the electrons produced by thermal agitation recombine wit holes.		
	(a)	(a) Both A and R are true and R is correct explanation of A		
	(b)	(b) Both A and R are true but R is not correct explanation of A		
	(c)	A is true but R is false		

(d) A is false but R is true

16. Fleming's left hand rule is used to find -					
	(a) direction of force on a current carrying conductor				
	(b) direction of flux in solenoid				
(c) direction of magnetic field due to a current carrying conductor				ying conductor	
	(d)	direction of induced emf			
17.	The	number of protons in a silicon atom are -			
	(a)	4	(b)	8	
	(c)	12	(d)	14	
18.	Asse	ertion (A): Hall effect is used to determine	whetl	her the semi- conductor is p or n type.	
	Reason (R): Under the influence of field, holes and electrons move in opposite direct			electrons move in opposite direction	
	(a)	Both A and R are true and R is correct exp	lanat	ion of A	
	(b)	Both A and R are true but R is not correct of	expla	nation of A	
	(c)	A is true but R is false			
	(d)	A is false but R is true			
19.	The	most important set of specifications of trans	form	er oil include -	
	(a)	dielectric strength and viscosity	(b)	dielectric strength and flash point	
	(c)	viscosity and flash point	(d)	flash point and viscosity	
20.	For i	isotopes of an element -			
	(a)		with	different mass	
	(b) The only difference in composition between isotopes of the same element is the number neutrons in the nucleus				
	(c)			-	
		proportions in which they normally occur in a	ature		
	(d)	All of these			
21.	N-ty	pe semiconductors are -			
	(a)	Negatively charged			
	(b) Produced when indium is added as an impurity to germanium				
	(c)	Produced when phosphorous is added as an i	impu	rity to silicon	
	(d)	None of these			
22.	Whi	ch of the following gives piezo-electric effect -			
	(a)	Mu metal	(b)	PVDF	
	(c)	Sapphire	(d)	Ferrites	
23.	23. The type of systems which are characterized by input and the output quantized at certain level called as -			nd the output quantized at certain levels are	
	(a)	analog	(b)	discrete	
	(c)	continuous	(d)	digital	
24.	Ane	xample of a discrete set of information/system	is -		
		the trajectory of the Sun		data on a CD	
	(c)	universe time scale	(d)	movement of water through a pip	
25	()	stem which is linear is said to obey the rules o	` '	⊘ rr	
-0.	-	scaling	(b)	additivity	
	` '	both scaling and additivity	(d)	homogeneity	
	\ /	\mathcal{L}	\ /	<i>-</i>	

26.	A tin	ne invariant system is a system whose outpu	ıt -	
	(a)	increases with a delay in input	(b)	decreases with a delay in input
	(c)	remains same with a delay in input	(d)	vanishes with a delay in input
27.	A sys	stem is said to be defined as non-causal, wh	ien -	
	-	the output at the present depends on the inp		an earlier time
	(b)	the output at the present does not depend o	n the	factor of time at all
	(c)	the output at the present depends on the inp	ut at	the current time
	(d)	the output at the present depends on the inp	out at	a time instant in the future
28. A system produces zero output for one input and same gives the same output			e gives the same output for several other	
	inpu	ts. What is the system called?		
	(a)	Non – invertible System	` '	Invertible system
	(c)	Non – causal system	(d)	Causal system
29.	29. Which of the following signals are monotonic in nature?			
	(a)	$1-\exp(-t)$	(b)	$1-\exp(\sin(t))$
	(c)	log(tan(t))	(d)	$\cos(t)$
30.	For t	he signal $x(t) = a - b*exp(-ct)$, what is the s	steady	state value, and the initial value?
	(a)	c, b	(b)	c, c-a
	(c)	a, a-b	(d)	b, a-b
31.	Pote	ntial difference in electrical terminology is	know	n as?
	(a)	Voltage	(b)	Current
	(c)	Resistance	(d)	Conductance
32.	The	circuit in which current has a complete path	to fl	ow is called circuit.
	(a)	short	(b)	open
	(c)	closed	(d)	open loop
33.	If the voltage-current characteristic is a straight line through the origin, then the element is satisfied to be?			nrough the origin, then the element is said
	(a)	Linear element	(b)	Non-linear element
	(c)	Unilateral element	(d)	Bilateral element
34.	How	many types of dependent or controlled sou	rces a	are there?
	(a)	1	(b)	2
	(c)	3	(d)	4
35.	If the	e resistances 1W, 2W, 3W, 4W are parallel, th	en th	e equivalent resistance is?
	(a)	0.46 ₩	(b)	0.48 W
	(c)	0.5 W	(d)	0.52 ₩
36.	For a	voltage source to be neglected, the termina	als ac	ross the source should be -
	(a)	replaced by inductor	(b)	short circuited
	(c)	replaced by some resistance	(d)	open circuited
37.	In ca	se of ideal current sources, they have -		
	(a)	zero internal resistance	(b)	low value of voltage
	(c)	large value of current	(d)	infinite internal resistance

38.	A practical voltage source can also be represented as -					
	(a)	a resistance in series with an ideal current	sour	ce		
	(b)	(b) a resistance in series with an ideal voltage source				
	(c)	a resistance in parallel with an ideal volta	ge so	urce		
	(d)	none of the mentioned				
39.	With some initial change at $t = 0+$, a capacitor will act as -					
	(a)	open circuit	(b)	short circuit		
	(c)	a current source	(d)	a voltage source		
40.	A voltage source of $300~V$ has internal resistance of 4W and supplies a load having the same resistance. The power absorbed by the load is -					
	(a)	1150 W	(b)	1250 W		
	(c)	5625 W	(d)	5000 W		
41.	In Su	In Superposition theorem, while considering a source, all other voltage sources are?				
	(a)	open circuited	(b)	short circuited		
	(c)	change its position	(d)	removed from the circuit		
42.	The maximum power is delivered from a source to its load when the load resistance is the source resistance.					
	(a)	greater than	(b)	less than		
	(c)	equal to	(d)	less than or equal to		
43.	If source impedance is complex, then maximum power transfer occurs when the load impedance is the source impedance.					
	(a)	equal to	(b)	negative of		
	(c)	complex conjugate of	(d)	negative of complex conjugate of		
44.	The dual pair of current is?					
	(a)	voltage	(b)	current source		
	(c)	capacitance	(d)	conductance		
45.	Tellegen's Theorem is valid for network?					
	(a)	linear or non-linear	(b)	passive or active		
	(c)	time variant or time invariant	(d)	all of these		
46.	For Tellegen's Theorem to satisfy, the algebraic sum of the power delivered by the source is					
	than power absorbed by all elements.					
	(a)	greater	(b)	less		
	(c)	equal	(d)	greater than or equal		
47.	Reciprocity Theorem is used to find the change in when the resistance is changed in the circuit.					
	(a)	Voltage	(b)	Voltage or current		
	(c)	Current	(d)	Power		
48.	Unde	er normal conditions a diode conducts current	wher	nitis -		
	(a)	reverse-biased	(b)	forward-biased		
	(c)	Avalanched	(d)	Saturated		

- 49. The boundary between p-type material and n-type material is called -
 - (a) a diode

(b) a reverse-biased diode

(c) a p-n junction

- (d) a forward-biased diode
- **50.** How much is the base-to-emitter voltage of a transistor in the "on" state?
 - (a) 0 V

(b) 0.7 V

 $(c) 0.7 \,\mathrm{mV}$

(d) Undefined

SECTION - B (Short answer type question) (100 Marks)

All questions carry equal marks of 5 each.

This Section should be answered only on the **Answer Sheet** provided.

- 1. What are resistors? Explain the advantages and disadvantages of carbon composition resistors.
- **2.** Temperature coefficients of some given samples of ceramic capacitors are expressed as N200, P150, and NPO. What do these inscriptions indicate?
- **3.** What are semiconductors? What are n-type and p-type semiconductors?
- **4.** When $R_1 = 100$ K, $\pm 20\%$ is connected across $R_2 = 10$ K, $\pm 5\%$ what will be the tolerance of the parallel combination? What do you deduce from the result?
- **5.** What materials are superconductors? Explain with examples.
- **6.** What is Zener diode? Draw its circuit symbol and characterization.
- 7. Calculate the reverse current of a silicon diode at a temperature of 27°C if a forward voltage of 0.5 V causes a current of 1 A.
- **8.** What are the Enhancement MOSFET and Depletion MOSFET?
- 9. Briefly describe the application of JFET as a Voltage Variable Resistors (VVR).
- **10.** What is Silicon Controlled Switch? How does it resemble a four layer diode?
- 11. What are Signum Function and Sinc function?
- **12.** What are the classifications of continuous time signals? Name them.
- 13. To implement the linear time invariant recursive system described by the difference equation, $y(n) = -\sum_{k=1}^{n} a_k y(n-k) + \sum_{k=0}^{M} b_k x(n-k)$ in direct form-I, how many number of delay elements and multipliers are required respectively?
- **14.** What is the z-transform of the finite duration signal $x(n) = \{2,4,5,7,0,1\}$?

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- 15. If $x(n) = x_R(n) + jx_I(n)$ is a complex sequence whose Fourier transform is given as $X(v) = X_R(v) + jX_I(v)$, then what is the value of $X_R(v)$?
- **16.** Which type of networks allows the physical separability of the network elements (resistors, inductors & capacitors) for analysis purpose and why?

- 17. How is the loop analysis different in application/functioning level as compared to Kirchoff's law?
- 18. How is the short circuit reverse transfer admittance (y_{12}) calculated in terms of current and voltage ratio?
- 19. What will be the value of a rectangular (complete incidence) matrix, if an associated branch is oriented towards the node?
- **20.** How is an insertion loss represented in terms of power ratio? Explain.

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